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Low defects, large area and high stability of all-inorganic lead halide perovskite CsPbBr_3 thin films with micron-grains via heat-spraying process for self-driven photodetector†

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All-inorganic lead halide perovskite CsPbBr_3 has important applications in photoelectronic devices such as photodetectors, LEDs and photovoltaic devices. However, preparing high-quality CsPbBr_3 thin films has proven to be challenging. In this study, we prepared all-inorganic lead halide perovskite CsPbBr_3 thin films with micron-grains (MG- CsPbBr_3 -TF) via a heat-spraying process (HSP) using a CsPbBr_3 -saturated solution (CsPbBr_3 -SS), and the films exhibited large area, low defects and high stability. The grain size of MG- CsPbBr_3 -TF was about 1–5 microns. The micron-sized grains in MG- CsPbBr_3 -TF enabled the absorption cutoff edge to be extended from 537 to 545 nm. In addition, the presence of fewer boundaries in MG- CsPbBr_3 -TF reduced the defects in MG- CsPbBr_3 -TF (the blue shift of luminescence). The response wavelengths of a low-cost and self-driven (zero-biased) photodetector based on MG- CsPbBr_3 -TF were from 330 to 600 nm. CsPbBr_3 thin films having a large area (10 cm × 10 cm) and micron-sized grains were also prepared by HSP and exhibited excellent stability (1944 h) in air ($T = 298$ K, 40% humidity). To the best of our knowledge, this is the first study of high-quality CsPbBr_3 thin films prepared by HSP. The results are of great interest for both fundamental research and practical applications of CsPbBr_3 in photodetectors, LEDs and photovoltaic devices.

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1. Introduction

Lead halide perovskite (LHP) materials have become a research hotspot because of their novel physical and chemical properties.^{1–4} Recently, organic–inorganic LHP material-based thin film solar cells have demonstrated high power conversion efficiencies (PCEs) of more than 22%,⁵ competing with commercially available silicon solar cells. Thus, organic–inorganic LHP materials have attracted widespread attention. However, the stability of organic–inorganic LHP materials is not ideal. One of the drawbacks of organic–inorganic LHP materials is that the three-dimensional crystal structure can be easily destroyed by moisture in the air. In addition, these materials do not exhibit very good thermal stability above 180 °C. The use of all-inorganic perovskites is one of the ways to improve the

stability of LHP. Compared to organic–inorganic LHP, all-inorganic LHP materials exhibit superior stability against moisture and temperature. An all-inorganic lead bromide perovskite (CsPbBr_3) material functions equally well as the organic one, in particular for generating high open circuit voltages, which is an important feature of solar cells.⁶ In addition, CsPbBr_3 is a direct band gap semiconductor, which meets most of the requirements for successful high-energy radiation detection of X-ray and gamma-ray radiation such as high attenuation, high resistivity, and significant photoconductivity response.⁷ Recently, CsPbBr_3 was also applied as the emitting layer in LEDs⁸ and as a novel photocatalyst to convert CO_2 into solar fuels in non-aqueous media.⁹ Therefore, CsPbBr_3 is a very promising optoelectronic material for many applications.^{10–13}

CsPbBr_3 nanocrystals were currently synthesized by injecting the organic cesium precursor Cs-oleate into a ligand solvent (oleic acid/oleylamine/1-octadecene).^{14,15} The CsPbBr_3 thin film with nano-grains (NG- CsPbBr_3 -TF) can be prepared by depositing CsPbBr_3 nanocrystals. However, the CsPbBr_3 thin film with micron-sized grains (MG- CsPbBr_3 -TF) has received less attention; nonetheless, it plays an important role in improving the performance of optoelectronic devices. Thus, CsPbBr_3 thin films with micron-sized grains urgently need to be developed. In

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this study, CsPbBr_3 thin films with micron-sized grains were formed from CsPbBr_3 -saturated solution (CsPbBr_3 -SS) by a heat-spraying process (HSP).

2. Experimental

2.1. Fabrication of CsPbBr_3 thin film with micron-sized grains by heat-spraying method

Patterned FTO-coated glass with sheet resistance of $15 \Omega \text{ sq}^{-1}$ was coated with a TiO_2 electronic collection layer (ECL) by spin-coating a TiO_2 organic sol at 3000 rpm for 30 s, followed by drying at 450°C for 120 min. Next, a CsPbBr_3 thin film with micron-sized grains was prepared by spraying CsPbBr_3 -saturated solution on the TiO_2 film at 200°C . Finally, carbon electrodes were prepared by doctor-blade coating a conductive carbon paste on the CsPbBr_3 layer using adhesive tapes as pattern and spaces, followed by drying at 80°C for 10 min. The size of the FTO/ TiO_2 / CsPbBr_3 /carbon electrode device was 1 cm^2 .

2.2. Fabrication of CsPbBr_3 thin films with nano-sized grains by the heat-spraying method

2.2.1. Preparation of Cs-oleate. Cs_2CO_3 (0.30 g) was added into 1 mL oleic acid. 1-Octadecene (18 mL) was then added into the above-mentioned solution. The mixed solution was heated to 120°C .

2.2.2. Preparation of CsPbBr_3 nanocrystals. PbBr_2 (0.10 g), 1 mL oleylamine, 5 mL 1-octadecene and 1 mL oleic acid were mixed. The mixed solution was heated to 200°C . Then, 1 mL Cs-oleate was injected into the above solution. Finally, this solution was cooled down to room temperature naturally. CsPbBr_3 nanocrystals were separated by centrifuging, and they were washed with butanol. The CsPbBr_3 thin film with nano-grains was prepared by spraying CsPbBr_3 nanocrystals in butanol on the TiO_2 electronic transport layer at 200°C .

2.3. Growth and characterizations of CsPbBr_3 single crystals

In a typical procedure, a 50 mL round-bottom flask was filled with 0.122 g Cs_2CO_3 and 1.8 mL 47% HBr aqueous solution; 0.115 g PbBr_2 was dissolved in this solution upon heating to 80°C using an oil bath for 30 min, which resulted in the formation of a suspension. This suspension was transferred to one side of an H tube using a plastic dropper. The suspension in the side of the H tube was left for 24 h until the precipitate and supernatant were separated. One side of the H tube contained the suspension, whereas the other side contained a light yellow solution. The H tube was placed in the dark for two weeks. Yellow crystal particles were obtained in the side of the H tube having the pale yellow solution.

2.4. Characterizations

The nanostructures of our films were characterized by scanning electron microscopy (SEM, Nova Nano SEM 450). UV-Vis absorption spectra and diffuse reflectance spectra were obtained using a UV-vis/NIR spectrometer (PerkinElmer, lambda, 750S). The photocurrent-time performances of the devices were

studied using an electrochemical workstation system (CHI760, Chenhua, and Shanghai) equipped with a solar simulator (IV5, PV Measurements, Inc., United States). The photocurrent-time with incident photon (wavelength) and frequency response was measured by an electrochemical workstation system (CHI760, Chenhua, and Shanghai) equipped with a quantum efficiency/spectral response (SR)/incident photon to current conversion efficiency (IPCE) measurement system (QEX10, PV Measurements, Inc., United States). External quantum efficiencies (EQE) were also measured by QEX10. The photocurrent-voltage performances of the devices were measured using a Keithley digital source meter (Keithley 2400, USA) equipped with a solar simulator (IV5, PV Measurements, Inc., USA).

3. Results and discussion

A schematic of the fabrication process of CsPbBr_3 film by HSP is shown in Fig. 1. The detailed processes can be seen in the experimental section. In a typical procedure, CsPbBr_3 suspension was obtained by the reaction between CsBr and PbBr_2 . Then, the suspension was transferred to one of the branches of H tube and left for 24 h until CsPbBr_3 precipitate and supernatant (CsPbBr_3 -saturated solution) were separated. The CsPbBr_3 -saturated solution was collected in the other branch of the H tube by slowly tilting it. Consequently, one side of the H tube had the CsPbBr_3 suspension, whereas the other had CsPbBr_3 -saturated solution. There are two advantages to the use of the H tube. First, the H tube can more effectively separate precipitate from the saturated solution. Second, CsPbBr_3 -saturated solution can be re-obtained by adding HBr solution by dissolution-precipitation equilibrium. The CsPbBr_3 -saturated solution can not only produce CsPbBr_3 thin films with micron-sized grains by a heat-spraying process (HSP) but also grow single crystals, as shown in Fig. 1.



CsPbBr_3 thin films can be prepared by spraying CsPbBr_3 -SS onto a heated FTO/ TiO_2 -ECL substrate. The color of CsPbBr_3 thin film is affected by the substrate (TiO_2 -ECL) temperature, as shown in Fig. 2a. The colour of the thin film prepared at 200°C on TiO_2 -ECL is orange (Fig. 2a). UV-visible absorption spectra and diffuse reflectance spectra of the films prepared under different temperatures are measured. The film prepared at 200°C on TiO_2 -ECL exhibits strong absorption from 250 to 510 nm, as shown in Fig. 2b. The absorbance of the film decreases sharply after 510 nm. The films prepared at 100 and 300°C on TiO_2 -ECL exhibit strong absorptions from 250 to 400 nm. The UV-visible diffuse reflectances of the thin films are also measured, as shown in Fig. 2c. The reflection intensity of the film prepared at 200°C on TiO_2 -ECL is significantly weaker from 250 nm to 510 nm, which corresponds to the strong UV-visible absorption from 250 to 510 nm. Meanwhile, the thin films prepared at 100 and 300°C on TiO_2 -ECL exhibit strong



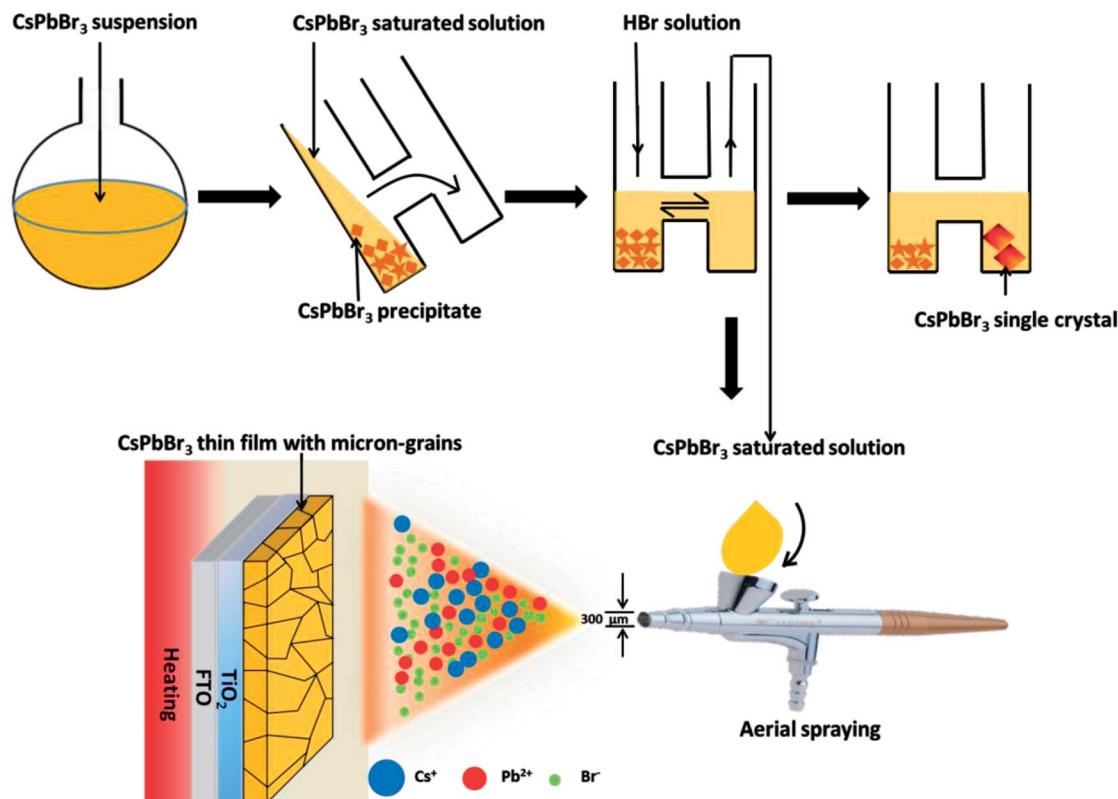


Fig. 1 Schematic of CsPbBr_3 thin film prepared by heat-spraying process using CsPbBr_3 -saturated solution.

reflectance in the visible range. This corresponds to weak UV-visible absorption from 250 to 510 nm. The above results indicate that it is impossible to form an orange CsPbBr_3 thin film at 100 or 300 °C on TiO_2 -ECL. To prove that the orange thin film prepared at 200 °C on TiO_2 -ECL is CsPbBr_3 , the crystal structure of the film is studied. The X-ray diffraction (XRD) pattern is

shown in Fig. 2d. A series of diffraction peaks are clearly observed. These diffraction peaks are consistent with the Joint Committee on Powder Diffraction Standards Cards (PDF#73-2463 for CsPbBr_3), revealing that the thin film prepared at 200 °C on TiO_2 -ECL has an orthorhombic crystal structure [Pmn (62) space group, $4.597 \times 9.72 \times 16.81 \text{ \AA}$, $90.0 \times 90.0 \times 90.0$].

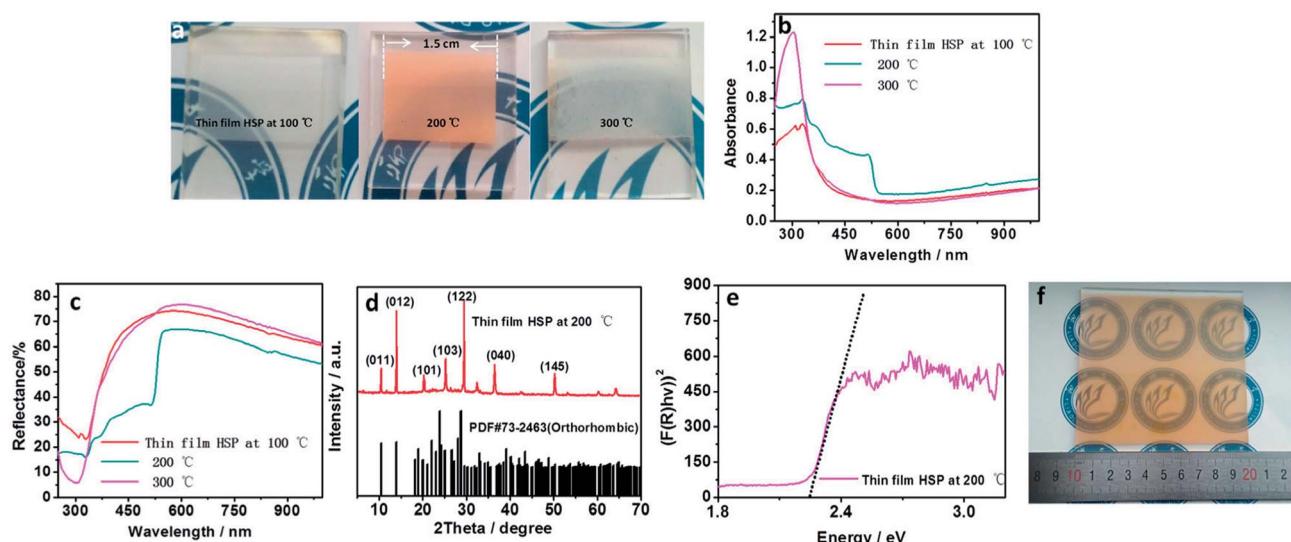


Fig. 2 (a) The colour of CsPbBr_3 thin film prepared on a substrate at different temperatures. (b) UV-visible absorption spectra of CsPbBr_3 thin film prepared on a substrate at different temperatures. (c) Diffuse reflectance spectra of CsPbBr_3 thin film prepared on a substrate at different temperatures. (d) XRD profiles of CsPbBr_3 thin film prepared on a substrate at 200 °C. (e) Transformed Kubelka–Munk spectrum of CsPbBr_3 thin film prepared on a substrate at 200 °C. (f) Large area (10 cm × 10 cm) of CsPbBr_3 film prepared by CsPbBr_3 -SS-HSP.

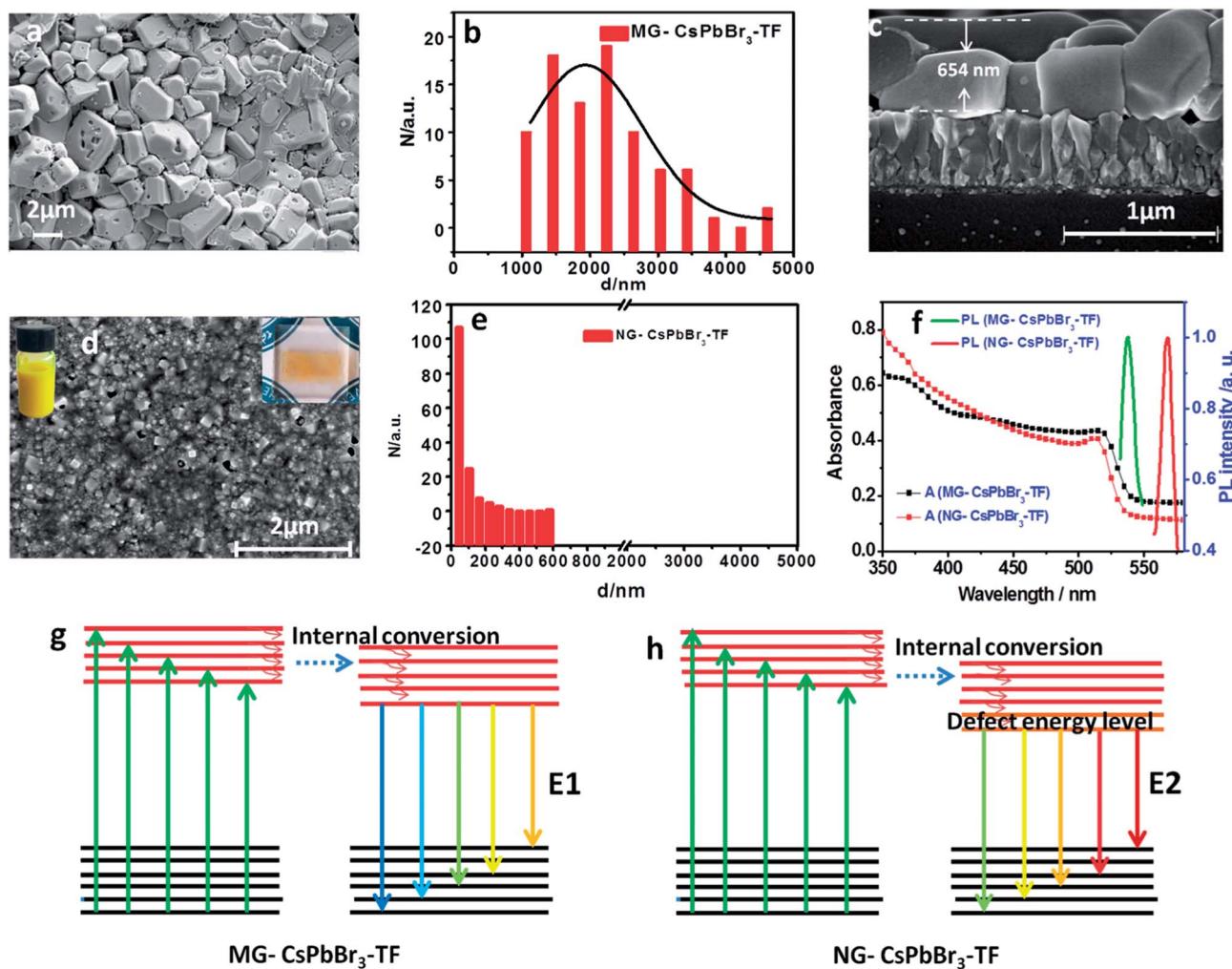


Fig. 3 (a) SEM images of MG-CsPbBr₃-TF. (b) The statistical distribution of grain size in MG-CsPbBr₃-TF. (c) Cross-sectional SEM images of MG-CsPbBr₃-TF. (d) SEM images of NG-CsPbBr₃-TF. (e) The statistical distribution of grain size in NG-CsPbBr₃-TF. (f) The photoluminescence (PL) spectra of MG-CsPbBr₃-TF and NG-CsPbBr₃-TF thin films. Schematic energy level diagrams of (g) MG-CsPbBr₃-TF and (h) NG-CsPbBr₃-TF.

The diffraction peaks at 10.6, 14.2, 20.4, 25.6, 29.7, 36.6, and 50.3° are assigned to the (011), (012), (101), (103), (122), (040), and (145) planes of orthorhombic CsPbBr₃, respectively. To obtain the bandgap of the CsPbBr₃ thin film sprayed at 200 °C on TiO₂-ECL, its diffuse reflectance spectrum is converted into a Kubelka–Munk spectrum.^{16,17} According to the Kubelka–Munk formula, $F(R) = (1 - R)^2/2R$, where R represents the percentage of reflection. The relationship between incident photon energy ($h\nu$) and E_g can be expressed as the transformed Kubelka–Munk equation $[F(R)h\nu]^p = A(h\nu - E_g)$, where E_g is the bandgap energy, A is the absorption constant, h is the Planck's constant, ν is the frequency of the light (s^{-1}) and P is the power index related to the optical absorption process. Theoretically, P is equal to 1/2 or 2 for an indirect or a direct allowed transition, respectively. According to literature, CsPbBr₃ can be regarded as having direct allowed transition. Thus, E_g for the CsPbBr₃ thin film is determined to be approximately 2.2 eV from the x -intercept of the linear part of $[F(R)h\nu]^2$ plot, as shown in Fig. 2e. The CsPbBr₃ film having a large area of 10 cm × 10 cm can also be prepared by CsPbBr₃-SS-HSP, as shown in Fig. 2f.

SEM (Fig. 3a) shows that the grains in CsPbBr₃ thin film are in micron scale. The statistical distribution of grain size indicates that the grain size in MG-CsPbBr₃-TF is 1–2 microns, as shown in Fig. 3b. The micron-sized grains with fewer grain boundaries are conducive to reduce the electron recombination and improve photoelectric performance of the device. The large coverage of MG-CsPbBr₃-TF can reduce the pinhole number and subsequently the possibility of a short circuit. The cross section of MG-CsPbBr₃-TF is examined by SEM, as shown in Fig. 3c. The thickness of MG-CsPbBr₃-TF is about 654 nm. In addition, the cross-sectional SEM also shows that the grains of MG-CsPbBr₃-TF are micrometer-sized. This result is consistent with the top-view results of SEM. As reference, CsPbBr₃ thin films with nanograins (NG-CsPbBr₃-TF) are prepared. The detailed fabrication processes are given in the Experimental section. The SEM image of NG-CsPbBr₃-TF is shown in Fig. 3d. The statistical distribution of grain size indicates that the grain size in NG-CsPbBr₃-TF is about 40 nm, as shown in Fig. 3e. The grain size is significantly smaller than that of MG-CsPbBr₃-TF. The large number of nano-grains in NG-CsPbBr₃-TF cause more defects, which

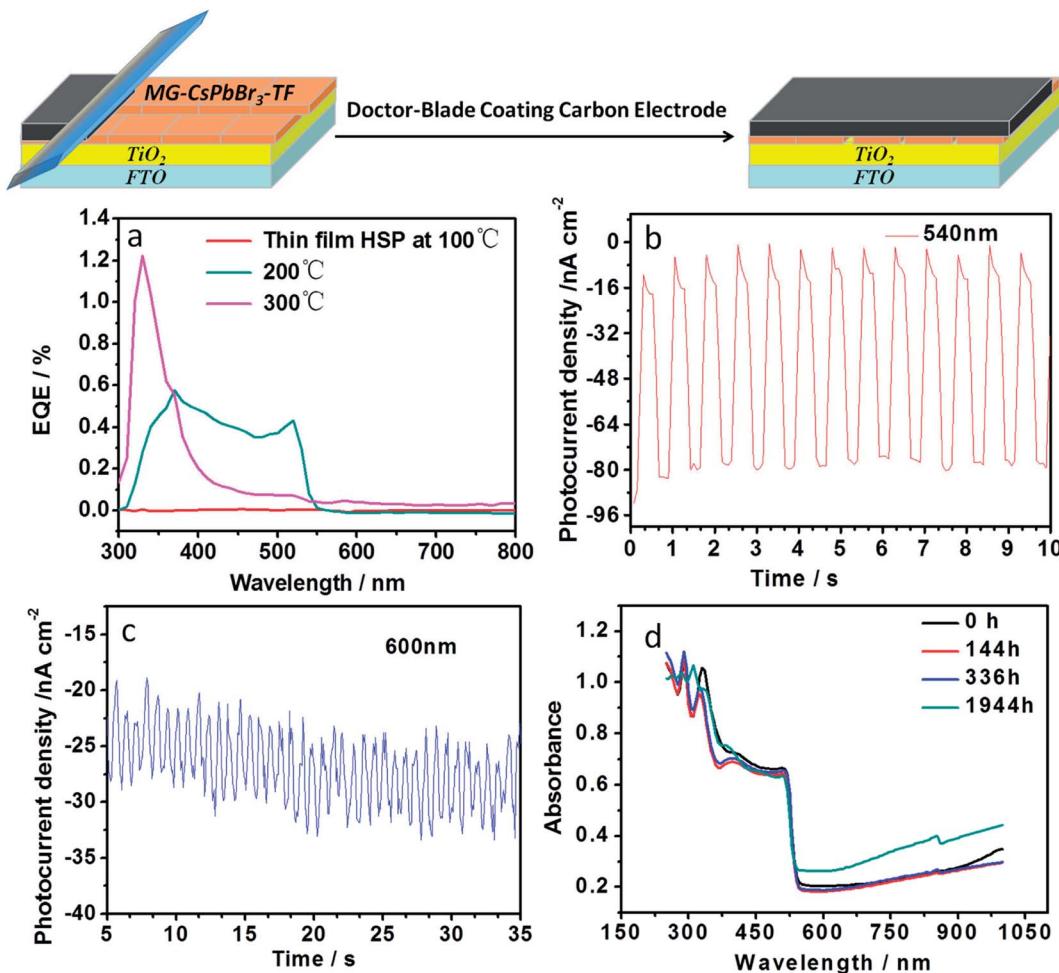


Fig. 4 (a) External quantum efficiency (EQE) of FTO/TiO₂/CsPbBr₃/carbon electrode device prepared on TiO₂-ECL at different temperatures. (b) Photocurrent density–time characteristics of the FTO/TiO₂/CsPbBr₃/carbon electrode device under 540 nm wavelength. (c) Photocurrent density–time characteristics of the FTO/TiO₂/CsPbBr₃/carbon electrode device under 600 nm wavelength. (d) UV-Vis absorption spectra of MG-CsPbBr₃-TF stored in the air ($T = 298$ K, 40% humidity).

results in deleterious photoelectric performance. The UV-Vis absorption spectra of MG-CsPbBr₃-TF and NG-CsPbBr₃-TF are shown in Fig. 3f. The absorption cutoffs of MG-CsPbBr₃-TF and NG-CsPbBr₃-TF are at 545 and 537 nm, respectively. A red shift in the absorption cutoff edge of MG-CsPbBr₃-TF is due to micron-sized grains, as shown in Fig. 3a and c. The absorption cutoff edge of MG-CsPbBr₃-TF is red shifted compared to that (535 nm) for CsPbBr₃ nanocubes¹⁸ and is close to that (548–555 nm) of CsPbBr₃ perovskite single crystals.^{19–21} The photoluminescence (PL) spectra of MG-CsPbBr₃-TF and NG-CsPbBr₃-TF are obtained, as shown in Fig. 3f. The excitation wavelength is set at 510 nm. The emission peaks of MG-CsPbBr₃-TF and NG-CsPbBr₃-TF are observed at 545 nm and 577 nm, respectively. The red shift in emission peaks of NG-CsPbBr₃-TF is due to the numerous grain boundaries, which are caused by the lower excited levels of NG-CsPbBr₃-TF, as shown in Fig. 3g and h.

To investigate the photoelectric properties of the MG-CsPbBr₃-TF thin film, photodetectors based on MG-CsPbBr₃-TF were prepared. The preparation procedure of such devices is shown in Fig. 4. The device structure is FTO/TiO₂/CsPbBr₃/carbon electrode. External quantum efficiencies (EQE) were

measured, as shown in Fig. 4a. The MG-CsPbBr₃-TF film exhibited EQE from 330 nm to 510 nm, which corresponded to the absorption range of the UV absorption spectrum (Fig. 2b). The device based on the thin film prepared at 300 °C on TiO₂-ECL only exhibited EQE from 300 nm to 400 nm. The device based on the thin film prepared at 100 °C on TiO₂-ECL exhibited zero EQE from 300 to 800 nm. The on-off performance of the devices based on MG-CsPbBr₃-TF under different wavelengths of the monochromatic light was investigated. The device exhibited significant on-off photocurrent responses with on-off operation at 330, 360, 390, 410, 420, 450, 480, 510, 540, 570 and 600 nm, as shown in Fig. 4b, c and S1.[†] As is well-known, the poor stability of organic-inorganic perovskites seriously restricts their commercialization. Meanwhile, all-inorganic perovskites are expected to have improved stability. The stability of MG-CsPbBr₃-TF stored in the air ($T = 298$ K, 40% humidity) was tested by obtaining its UV absorption spectrum. No clear change in the absorption intensity was observed after nearly 2000 h of storage. The device stability data are shown in Fig. S2.[†] The device placed in the air for 7 months still exhibited clear photoresponse under AM1.5, 100 mW cm⁻² simulated

illumination. These results confirmed that MG-CsPbBr₃-TF possessed good stability. In addition, CsPbBr₃ single crystals were prepared from CsPbBr₃/HBr supernatant, as shown in Fig. S3.† The thermal stability of CsPbBr₃ single crystals was assessed by thermogravimetric analysis (Fig. S4†). The results indicated that CsPbBr₃ single crystal materials begin to decompose at 500 °C. Compared with organic-inorganic hybrid CH₃NH₃PbI₃ materials, inorganic CsPbBr₃ perovskites indeed exhibited good thermal stability.

Conflicts of interest

There are no conflicts to declare.

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